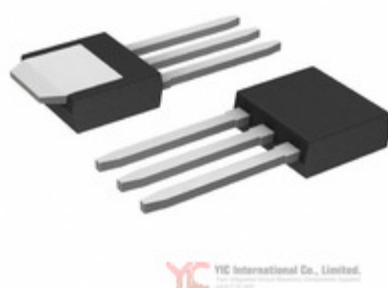






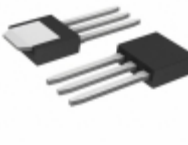
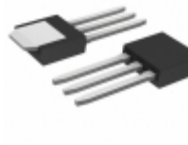

	<p>Hersteller-Teilenummer: NTD50N03R-1G</p>
	<p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p>
	<p>Teil der Beschreibung: MOSFET N-CH 25V 7.8A IPAK</p>
	<p>Datenblätter:  NTD50N03R-1G.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 5000 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	NTD50N03R-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 25V 7.8A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Stub Leads, IPak
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.5W (Ta), 50W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	7.8A (Ta), 45A (Tc)
Rds On (Max) @ Id, Vgs	12 mOhm @ 30A, 11.5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 11.5V
Eingabekapazität (Ciss) (Max) @ Vds	750pF @ 12V
Verpackung	Tube



















































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 <p>NTD50N03RT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A DPAK</p>	 <p>NTD4979N-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9.4A IPAK TRIMME</p>	 <p>NTD50N03R-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A IPAK</p>	 <p>NTD50N03T4G O NTD50N03T4G O</p>

heiße Teile

Mehr

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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